

200-V half-bridge driver with shutdown and V_{CC} & V_{BS} UVLO

Features

- Gate drive supplies up to 20 V per channel
- Undervoltage lockout for V_{CC} , V_{BS}
- 3.3 V, 5 V, 15 V input logic compatible
- Tolerant to negative transient voltage
- Designed for use with bootstrap power supplies
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- Internal set deadtime
- High-side output in phase with input
- Shutdown input turns off both channels
- -40°C to 125°C operating range
- RoHS compliant

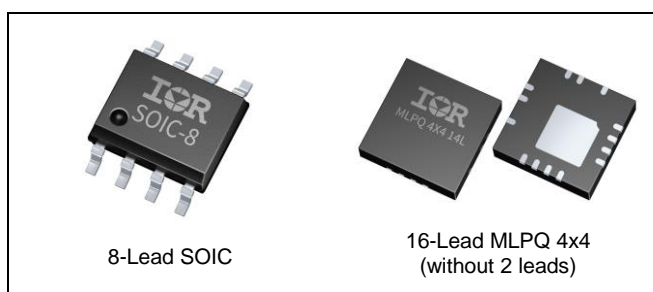
Product Summary

V_{OFFSET}	$\leq 200V$
V_{OUT}	10 V – 20 V
I_{O+} & I_{O-} (typ.)	290 mA & 600 mA
t_{ON} & t_{OFF} (typ.)	680 ns & 150 ns
Deadtime (typ.)	520 ns

Description

The IRS2008 is a high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 200 V. Propagation delays are matched to simplify the HVIC's use in high frequency applications.

Package Options

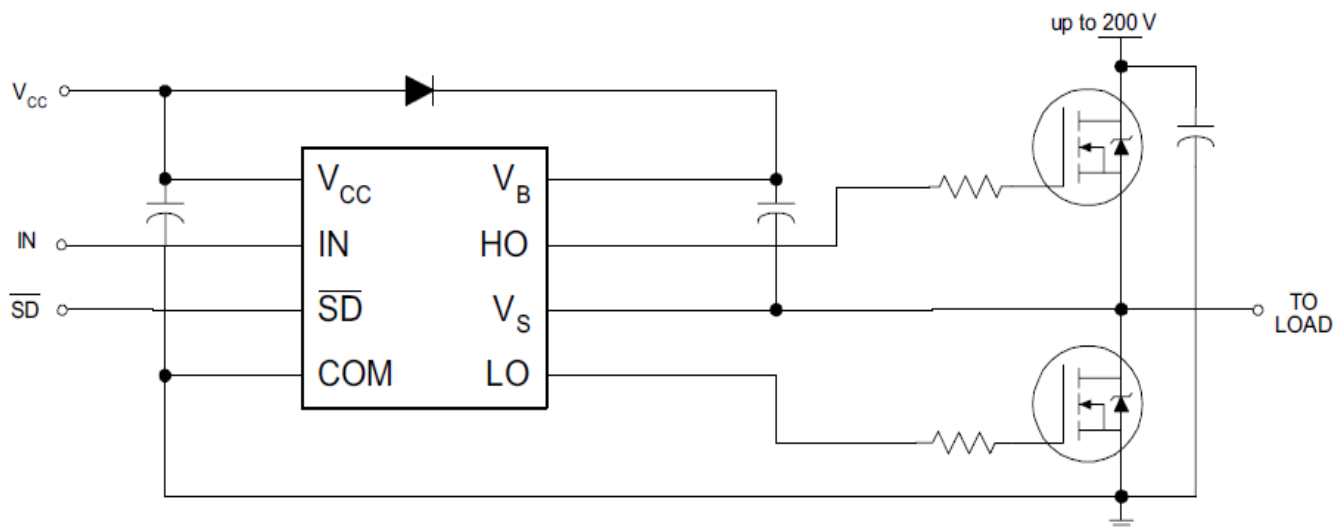


Typical Applications

- Appliance motor drives, Stepper motor, Servo drives
- Micro inverter drives
- General purpose three phase inverters
- Light electric vehicles (e-bikes, e-scooters, e-toys)
- Wireless Charging
- General battery driven applications

Base Part Number	Package Type	Standard Pack		Orderable Part Number
		Form	Quantity	
IRS2008S	8-Lead SOIC	Tape and Reel	2500	IRS2008STRPBF
		Tube/Bulk	95	IRS2008SPBF
IRS2008M	14-Lead MLPQ 4x4	Tape and Reel	3000	IRS2008MTRPBF

Typical Connection Diagram



(Refer to Lead Assignments for correct pin configuration). This diagram shows electrical connections only. Please refer our Application Notes & DesignTips for proper circuit board layout.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V_{CC}	Low side supply voltage	-0.3	25 [†]	V
V_{IN}	Logic input voltage (IN & \overline{SD})	COM - 0.3	$V_{CC} + 0.3$	
V_B	High-side floating well supply voltage	-0.3	225	
V_S	High-side floating well supply return voltage	$V_B - 25$	$V_B + 0.3$	
V_{HO}	Floating gate drive output voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{LO}	Low-side output voltage	COM - 0.3	$V_{CC} + 0.3$	
COM	Power ground	$V_{CC} - 25$	$V_{CC} + 0.3$	
dV_S/dt	Allowable V_S offset supply transient relative to COM	—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25^\circ\text{C}$	8-Lead SOIC	0.625	W
		14-Lead MLPQ 4x4	2.08	
R_{thJA}	Thermal resistance, junction to ambient	8-Lead SOIC	200	$^\circ\text{C/W}$
		14-Lead MLPQ 4x4	36	
T_J	Junction temperature	—	150	$^\circ\text{C}$
T_S	Storage temperature	-55	150	
T_L	Lead temperature (soldering, 10 seconds)	—	300	

[†] All supplies are tested at 25V.

Recommended Operating Conditions

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The offset rating is tested with supplies of $(V_{CC} - \text{COM}) = (V_B - V_S) = 15\text{V}$.

Symbol	Definition	Min	Max	Units
V_{CC}	Low-side supply voltage	10	20	V
V_{IN}	Logic input voltage (IN & \overline{SD})	0	V_{CC}	
V_B	High-side floating well supply voltage	$V_S + 10$	$V_S + 20$	
V_S	High-side floating well supply offset voltage [†]	COM - 8 [†]	200	
V_{HO}	Floating gate drive output voltage	V_S	V_B	
V_{LO}	Low-side output voltage	COM	V_{CC}	
T_A	Ambient temperature	-40	125	$^\circ\text{C}$

[†] Logic operation for V_S of -8 V to 200 V. Logic state held for V_S of -8 V to $-V_{BS}$. Please refer to Design Tip DT97-3 for more details.

Static Electrical Characteristics

($V_{CC} - COM$) = ($V_B - V_S$) = 15V. $T_A = 25^\circ\text{C}$ unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to respective V_S and COM and are applicable to the respective output leads HO or LO. The V_{CCUV} parameters are referenced to COM. The V_{BSUV} parameters are referenced to V_S .

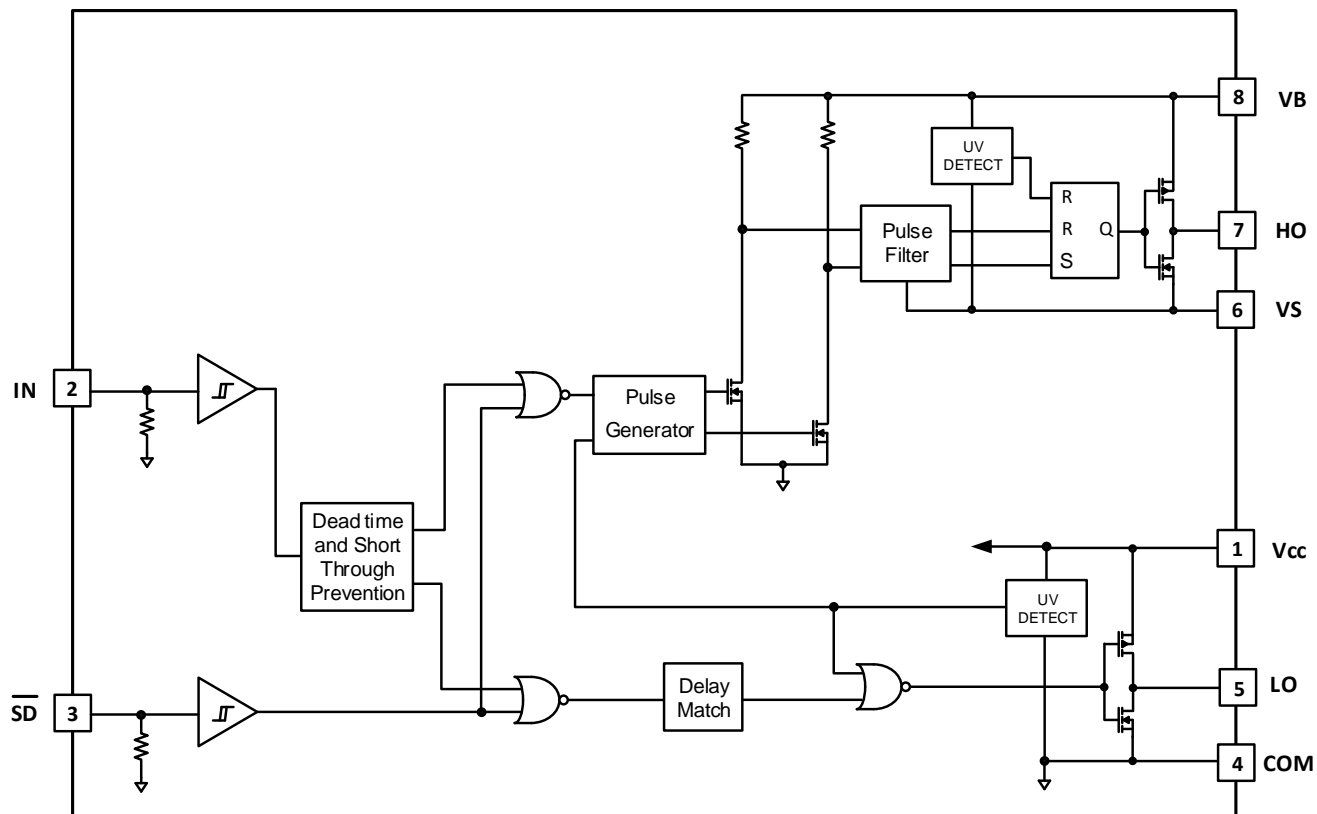
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{BSUV+}	V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V_{BSUV-}	V_{BS} supply undervoltage negative going threshold	7.4	8.2	9		
V_{BSUVHY}	V_{BS} supply undervoltage hysteresis	—	0.7	—		
V_{CCUV+}	V_{CC} supply undervoltage positive going threshold	8.0	8.9	9.8		
V_{CCUV-}	V_{CC} supply undervoltage negative going threshold	7.4	8.2	9		
V_{CCUVHY}	V_{CC} supply undervoltage hysteresis	—	0.7	—		
I_{LK}	High-side floating well offset supply leakage	—	—	50	μA	$V_B = V_S = 200\text{V}$
I_{QBS}	Quiescent V_{BS} supply current	—	45	75		All inputs are in the off state
I_{QCC}	Quiescent V_{CC} supply current	—	300	520		
V_{OH}	High level output voltage drop, $V_{BIAS}-V_O$	—	0.05	0.2	V	$I_O = 2\text{ mA}$
V_{OL}	Low level output voltage drop, V_O	—	0.02	0.1		
I_{O+}	Output high short circuit pulsed current	200	290	—	mA	$V_O = 0\text{V}$ $PW \leq 10\mu\text{s}$
I_{O-}	Output low short circuit pulsed current	420	600	—		$V_O = 15\text{V}$ $PW \leq 10\mu\text{s}$
V_{IH}	Logic "1" (HO) & Logic "0" (LO) input voltage	2.5	—	—	V	$V_{CC}=10\text{V to }20\text{V}$
V_{IL}	Logic "0" (HO) & Logic "1" (LO) input voltage	—	—	0.8		
$V_{SD,TH+}$	SD input positive going threshold	2.5	—	—		
$V_{SD,TH-}$	SD input negative going threshold	—	—	0.8		
I_{IN+}	Logic "1" Input bias current	—	3	10	μA	$V_{IN} = 5\text{V}$
I_{IN-}	Logic "0" Input bias current	—	—	5		$V_{IN} = 0\text{V}$

Dynamic Electrical Characteristics

$V_{CC} = V_B = 15\text{V}$, $V_S = COM$, $T_A = 25^\circ\text{C}$, and $C_L = 1000\text{pF}$ unless otherwise specified.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{ON}	Turn-on propagation delay	—	680	870	ns	$V_S = 0\text{V or }200\text{V}$
t_{OFF}	Turn-off propagation delay	—	150	220		
t_{SD}	Shutdown propagation delay	—	160	220		
t_R	Turn-on rise time	—	70	170		$V_S = 0\text{V}$
t_F	Turn-off fall time	—	30	90		
DT	Deadtime, LS turn-off to HS turn-on & HS turn-on to LS turn-off	400	520	650		
MT	Delay matching time (t_{ON} , t_{OFF})	—	—	60		

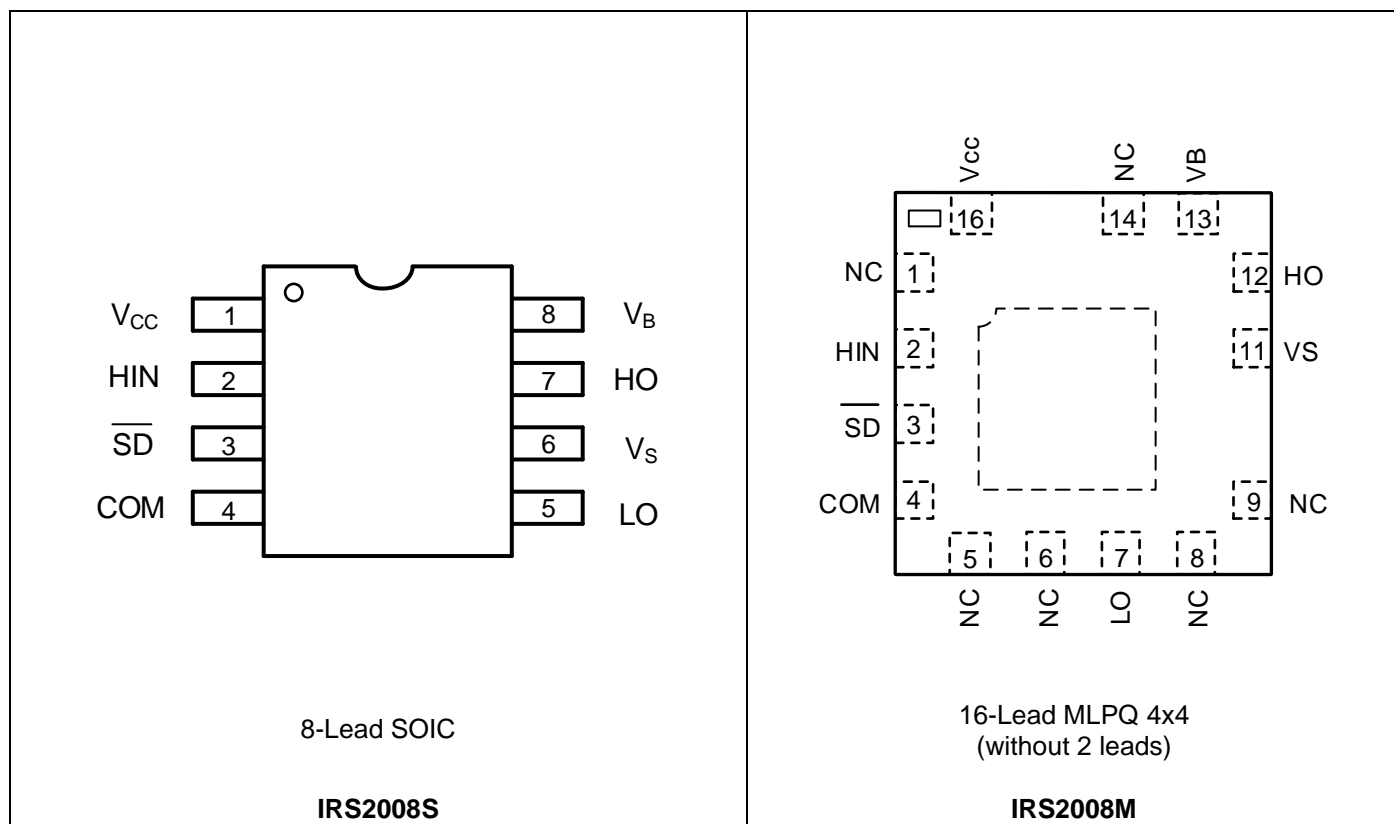
Functional Block Diagram



Lead Definitions

Symbol	Description
V _{CC}	Low-side and logic supply voltage
V _B	High-side gate drive floating supply
V _S	High voltage floating supply return
IN	Logic inputs for high and low side gate driver output (HO and LO), in phase with HO
\overline{SD}	Logic inputs for shutdown
HO	High-side driver output
LO	Low-side driver output
COM	Low-side gate drive return

Lead Assignments



Application Information and Additional Details

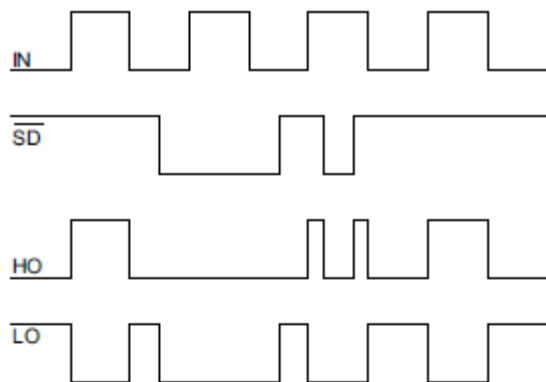


Figure 1. Input/Output Timing Diagram

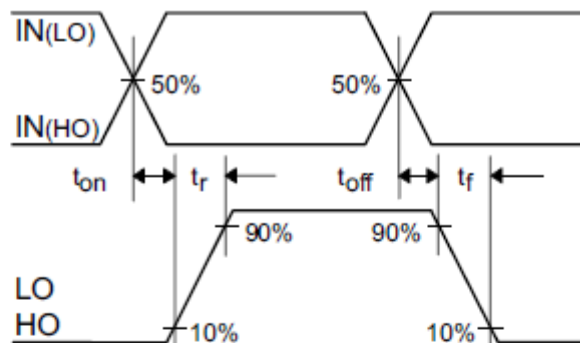


Figure 2. Switching Time Waveform Definitions

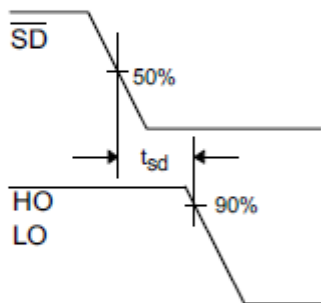


Figure 3. Shutdown Waveform Definitions

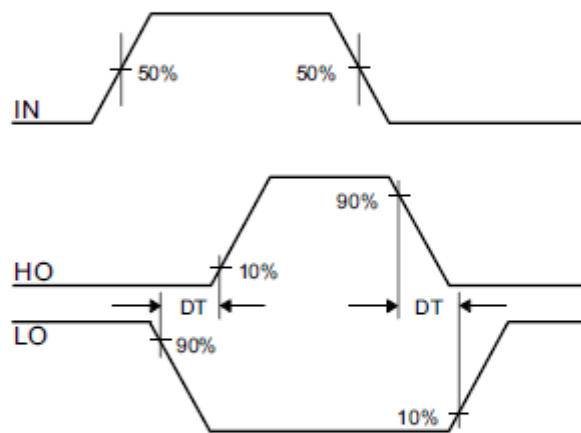


Figure 4. Deadtime Waveform Definitions

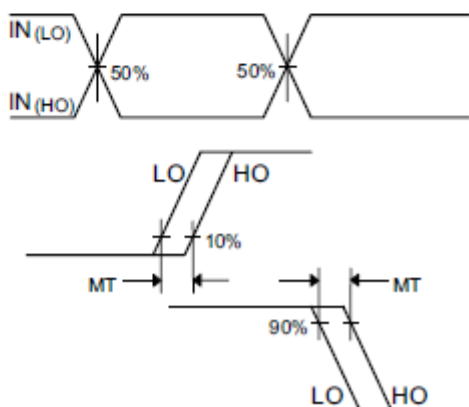


Figure 5. Delay Matching Waveform Definitions

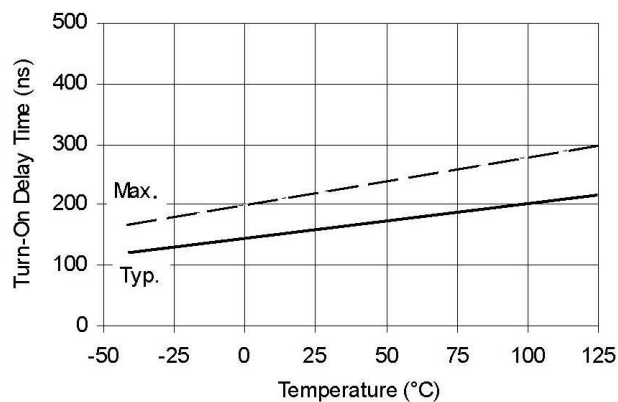


Figure 6A. Turn-On Time vs. Temperature

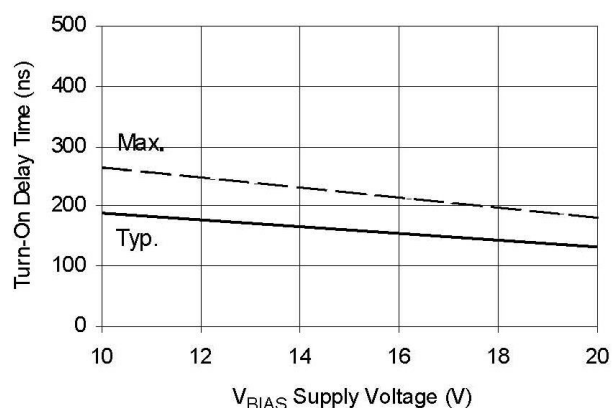


Figure 6B. Turn-On Time vs. Supply Voltage

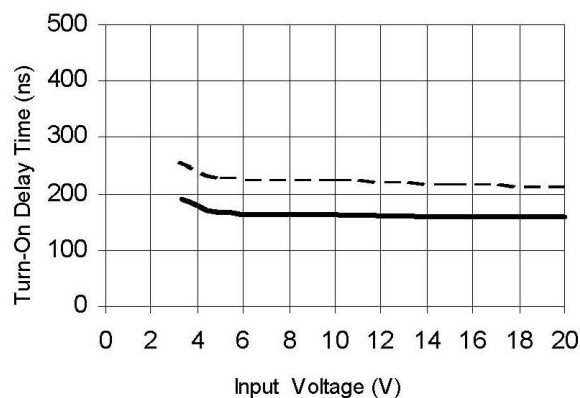


Figure 6C. Turn-On Time vs. Input Voltage

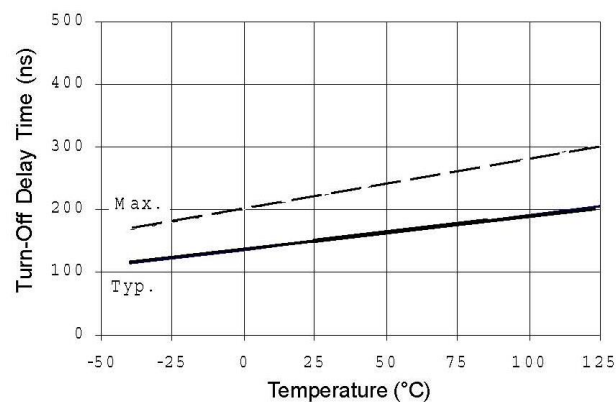


Figure 7A. Turn-Off Time vs. Temperature

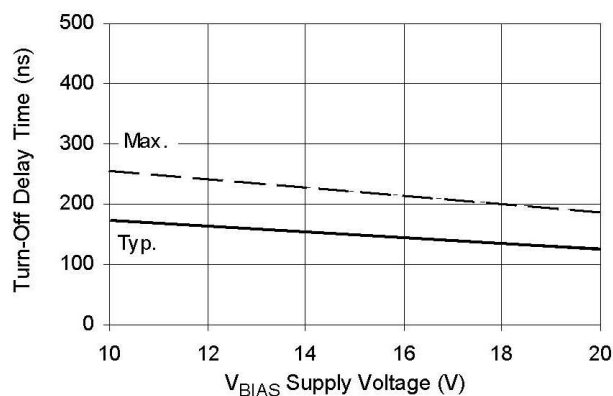


Figure 7B. Turn-Off Time vs. Supply Voltage

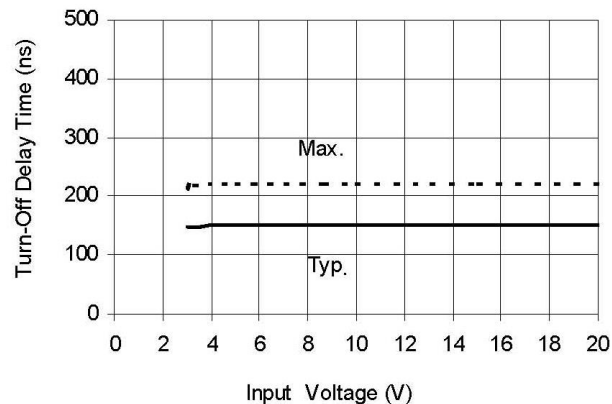


Figure 7C. Turn-Off Time vs. Input Voltage

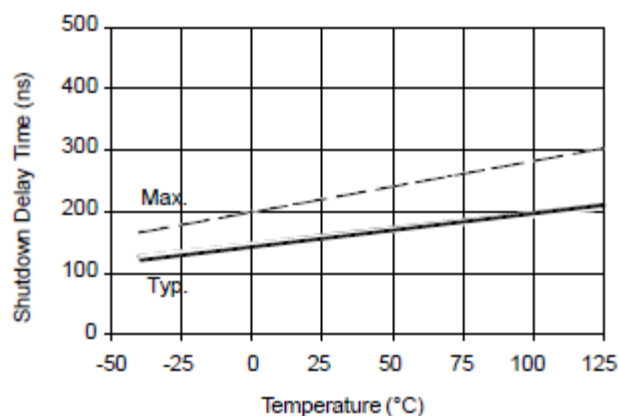


Figure 8A. Shutdown Time vs. Temperature

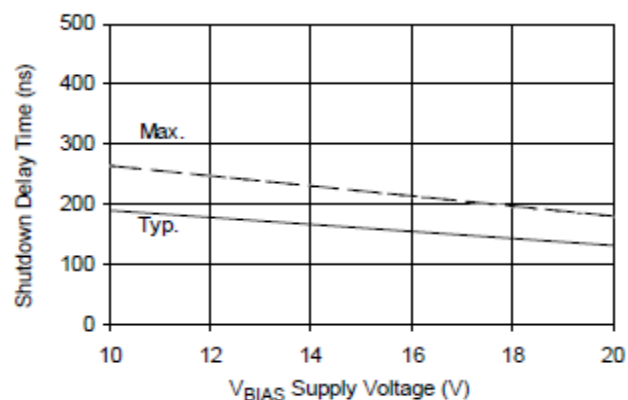


Figure 8B. Shutdown Time vs. Voltage

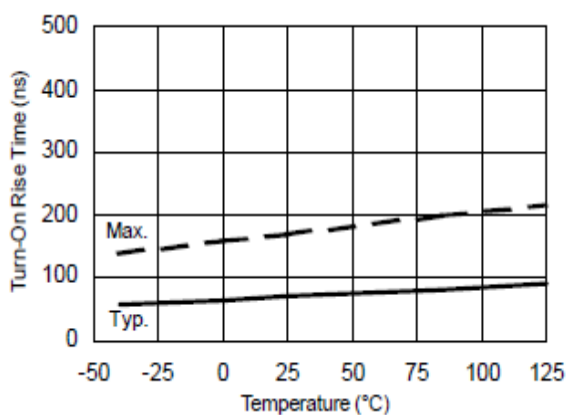


Figure 9A. Turn-On Rise Time vs. Temperature

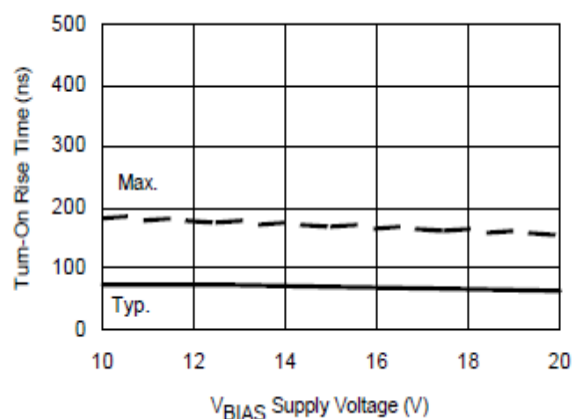


Figure 9B. Turn-On Rise Time vs. Voltage

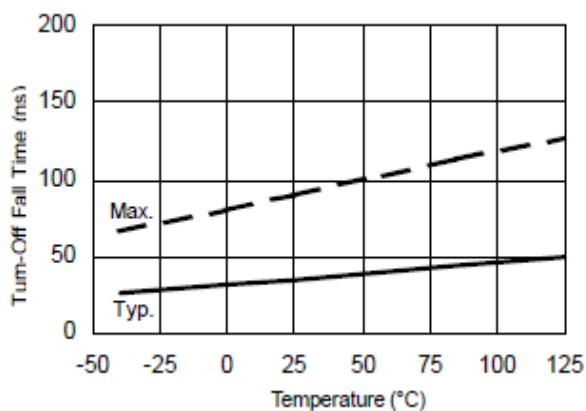


Figure 10A. Turn-Off Fall Time vs. Temperature

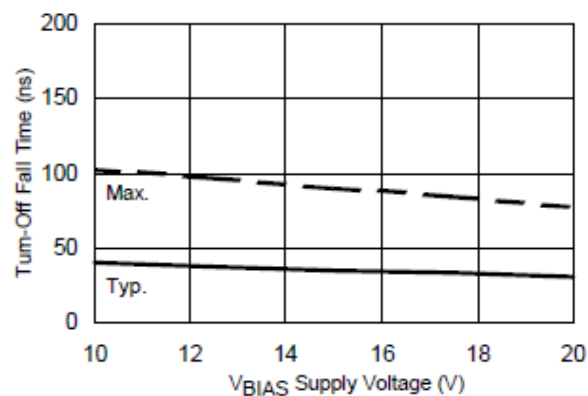


Figure 10B. Turn-Off Fall Time vs. Voltage

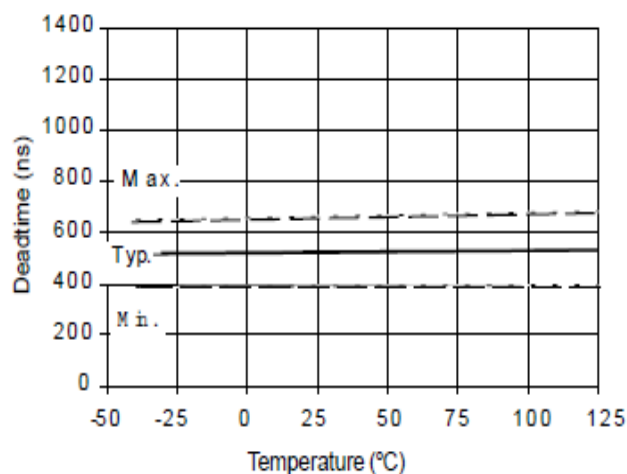


Figure 11A. Deadtime vs. Temperature

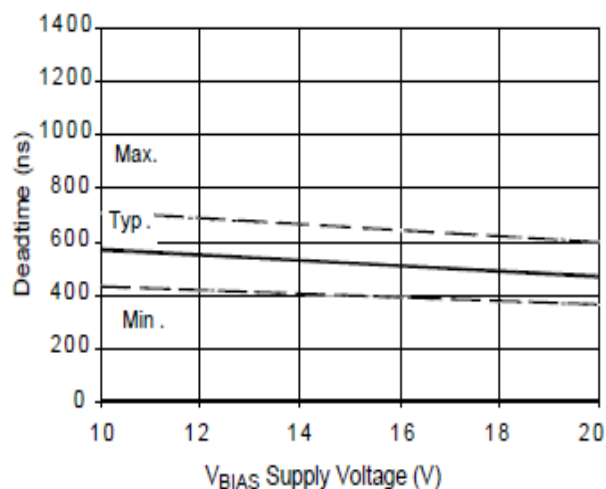


Figure 11B. Deadtime vs. Voltage

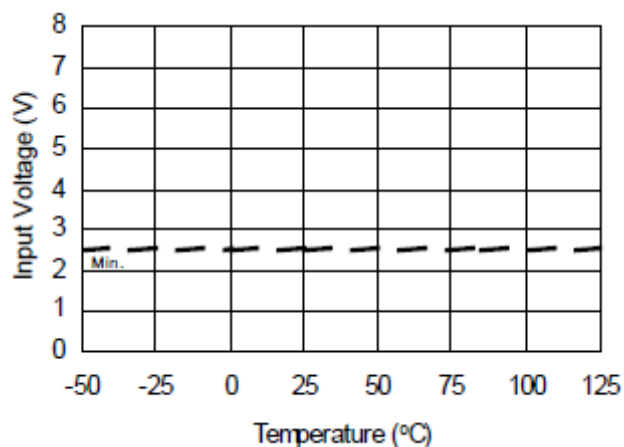


Figure 12A. Logic "1" Input Voltage vs. Temperature

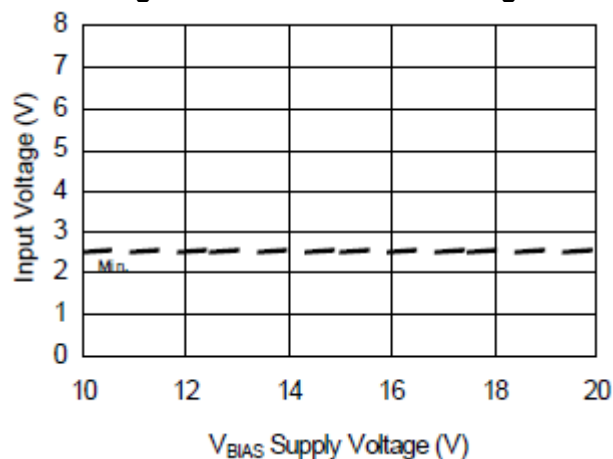


Figure 12B. Logic "1" Input Voltage vs. Voltage

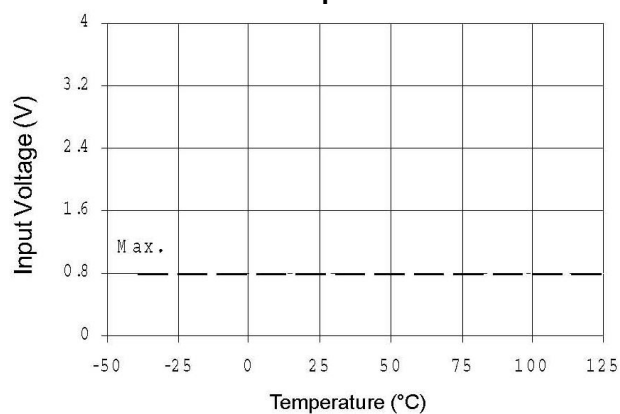


Figure 13A. Logic "0"(HO) & Logic "1"(LO) & Active SD Input Voltages vs. Temperature

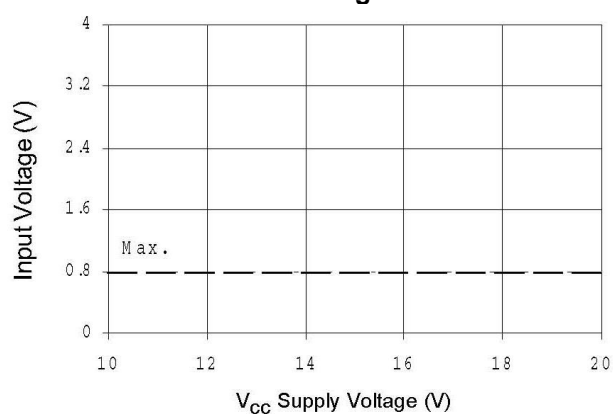


Figure 13B. Logic "0"(HO) & Logic "1"(LO) & Active SD Input Voltages vs. Supply Voltage

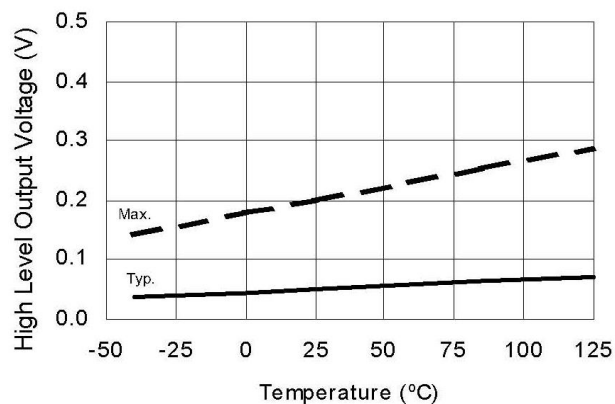


Figure 14A. High Level Output Voltage vs. Temperature

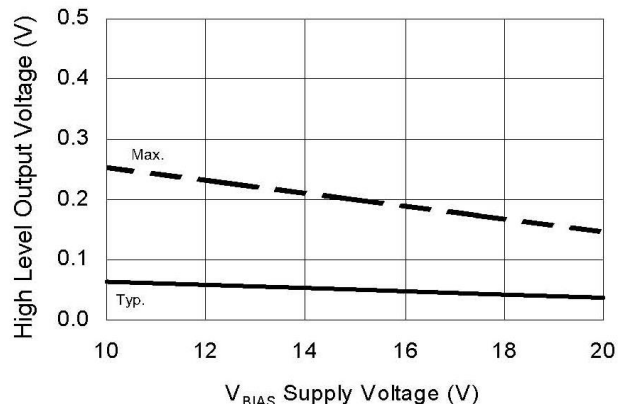


Figure 14B. High Level Output Voltage vs. Supply Voltage

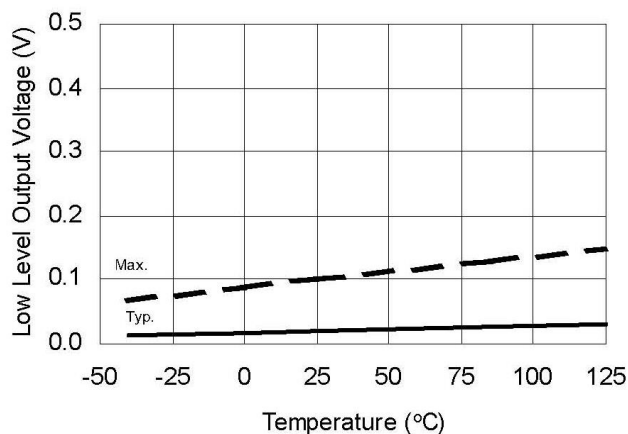


Figure 15A. Low Level Output Voltage vs. Temperature

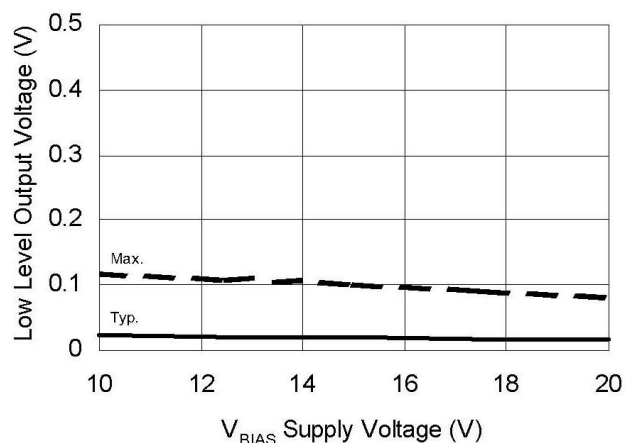


Figure 15B. Low Level Output Voltage vs. Supply Voltage

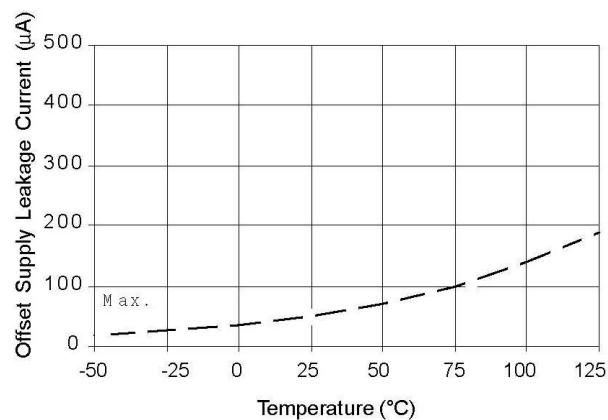


Figure 16A. Offset Supply Current vs. Temperature

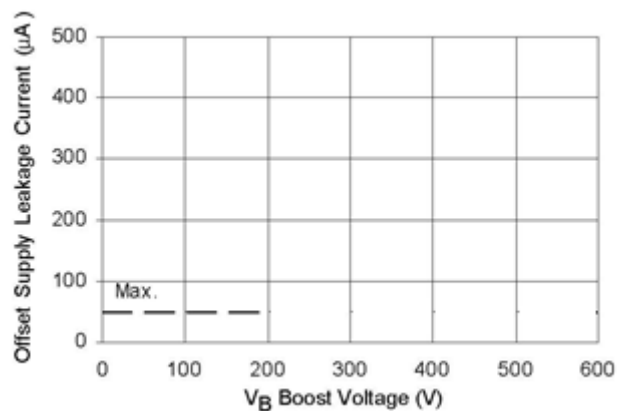


Figure 16B. Offset Supply Current vs. Voltage

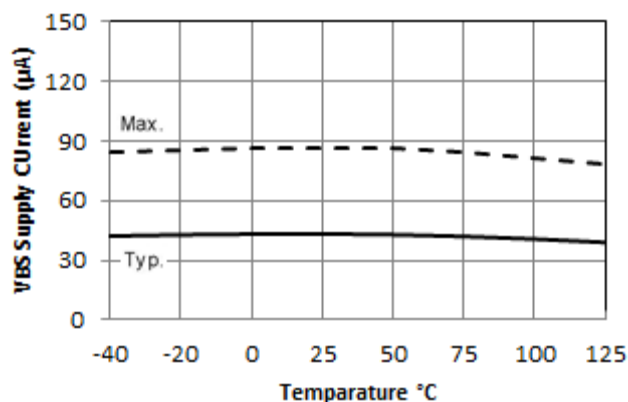


Figure 17A. V_{BS} Supply Current vs. Temperature

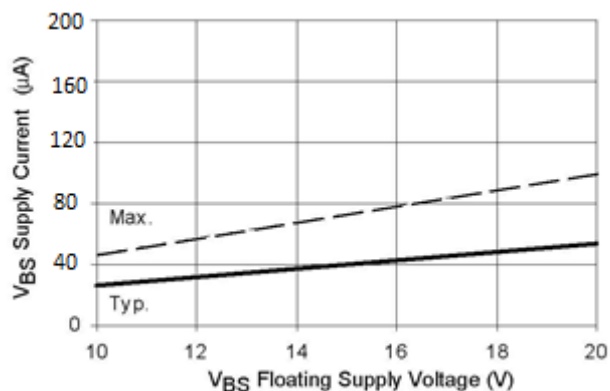


Figure 17B. V_{BS} Supply Current vs. Voltage

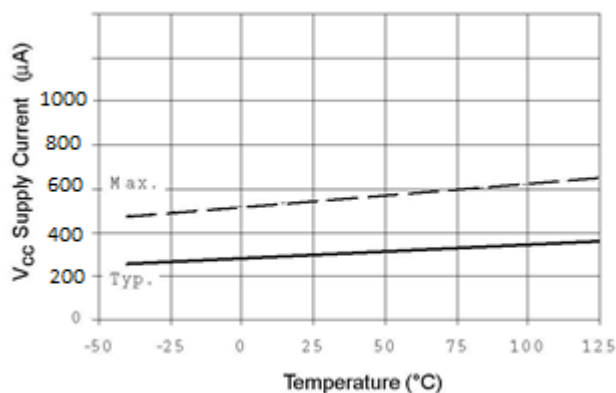


Figure 18A. V_{CC} Supply Current vs. Temperature

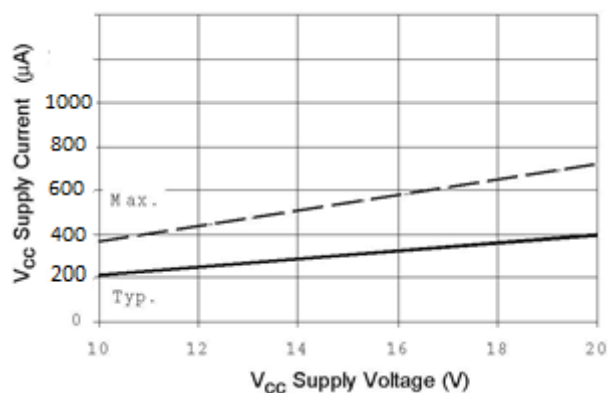


Figure 18B. V_{CC} Supply Current vs. Voltage

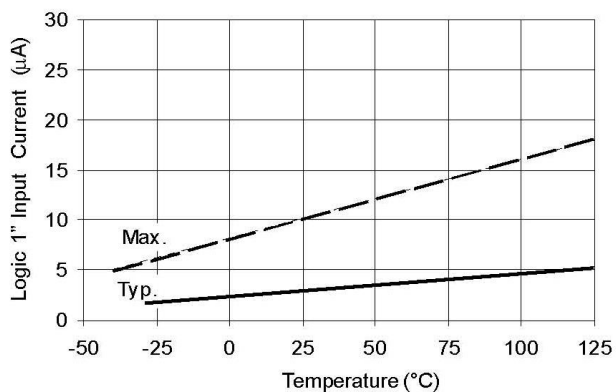


Figure 19A. Logic "1" Input Current vs. Temperature

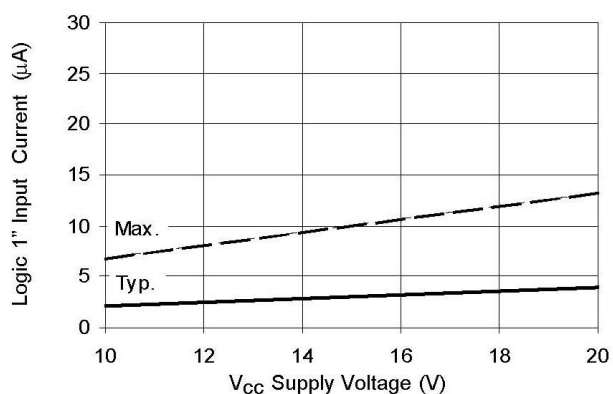


Figure 19B. Logic "1" Input Current vs. Voltage

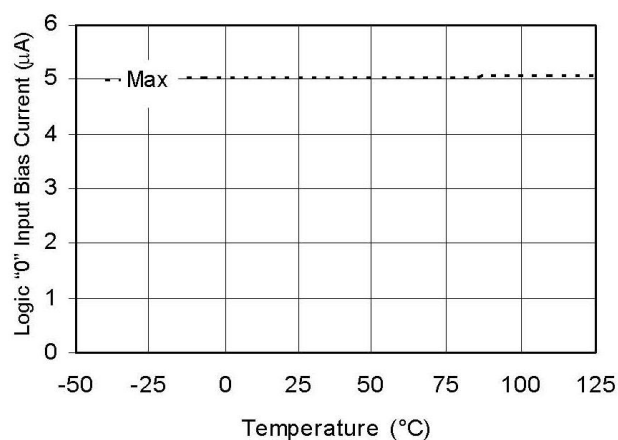


Figure 20A. Logic "0" Input Bias Current

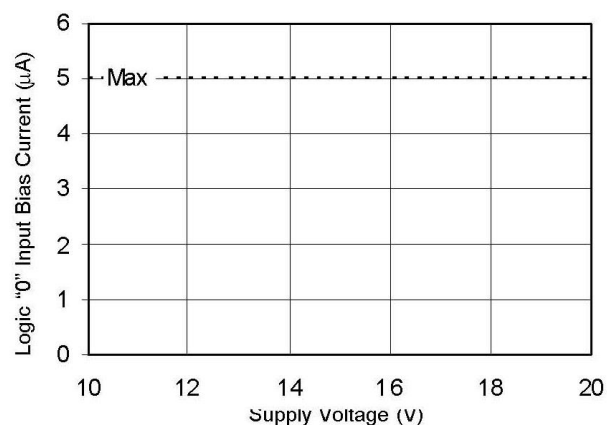


Figure 20B. Logic "0" Input Bias Current

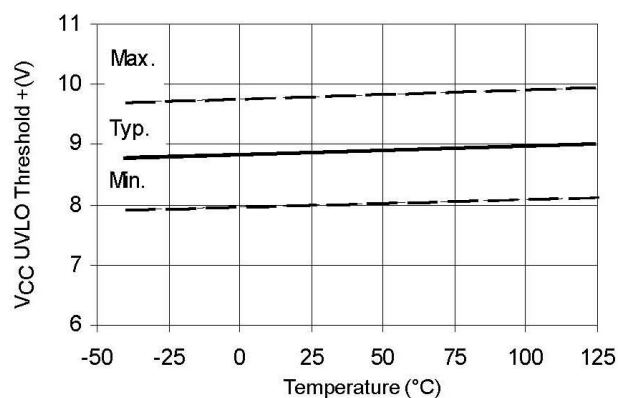


Figure 21A. V_{CC}\V_{BS} Undervoltage Threshold(+) vs. Temperature

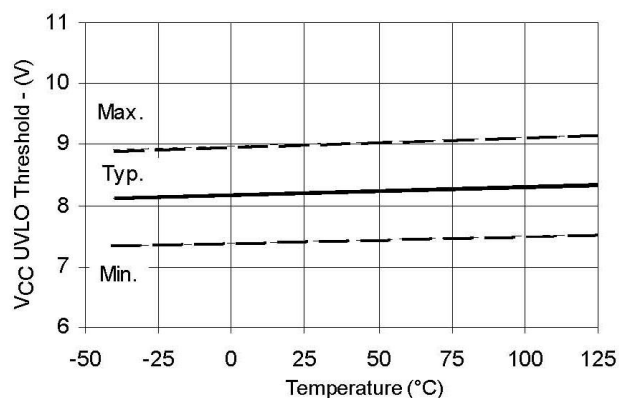


Figure 21B. V_{CC}\V_{BS} Undervoltage Threshold(-) vs. Temperature

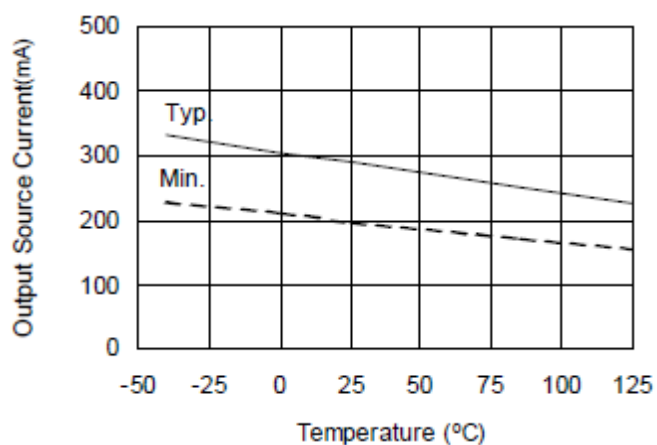


Figure 22A. Output Source Current vs. Temperature

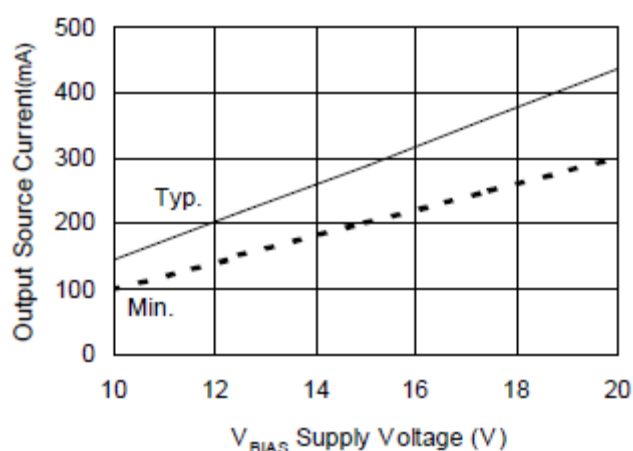


Figure 22B. Output Source Current vs. Supply Current

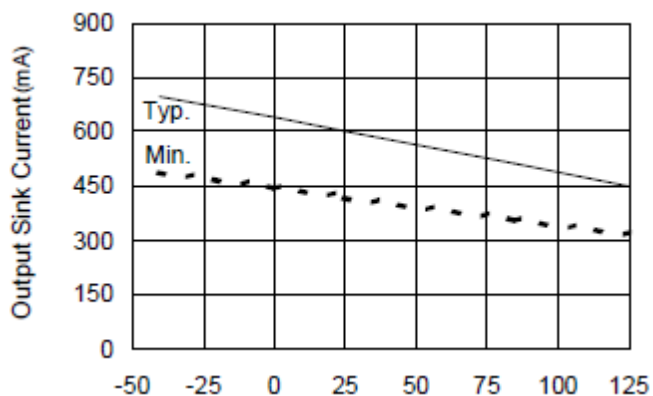


Figure 23A. Output Sink Current vs. Temperature

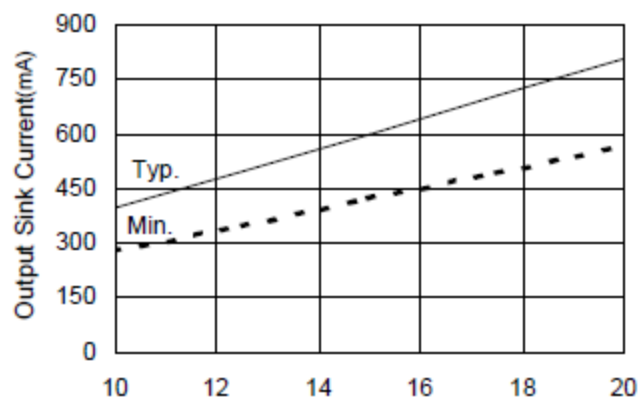


Figure 23B. Output Sink Current vs. Supply Voltage

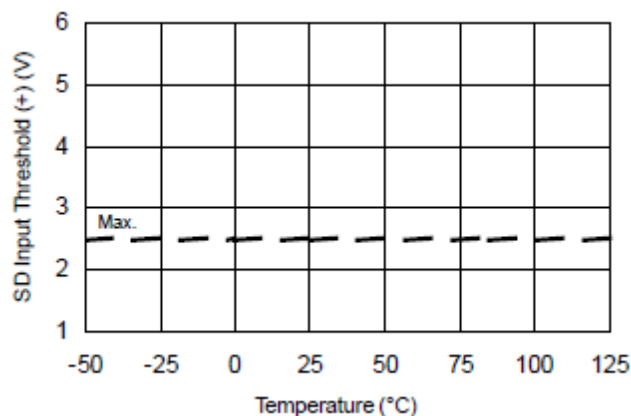


Figure 24A. SD input Positive Going Threshold(+) vs. Temperature

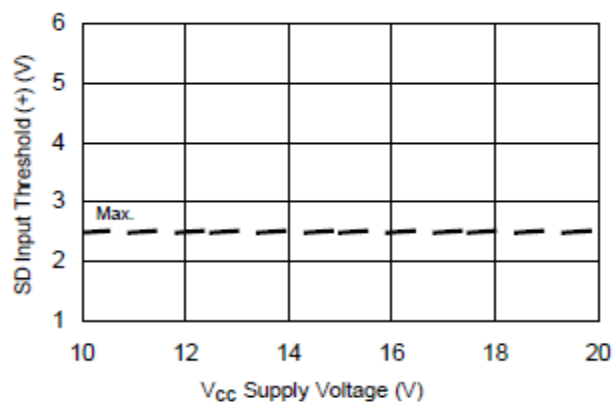


Figure 24B. SD input Positive Going Threshold(+) vs. Supply Voltage

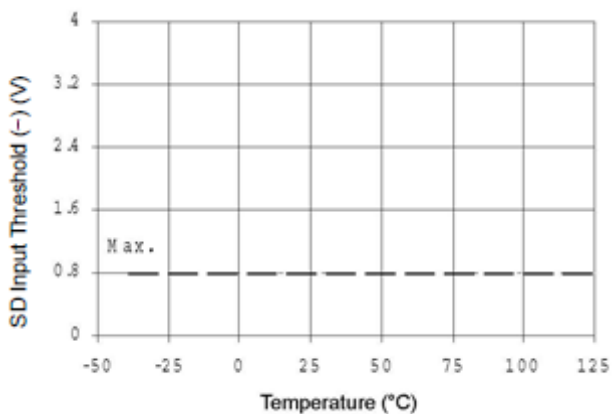


Figure 25A. SD input Negative Going Threshold(-) vs. Temperature

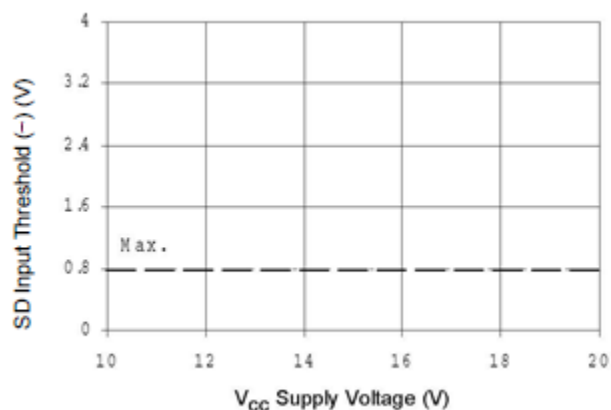
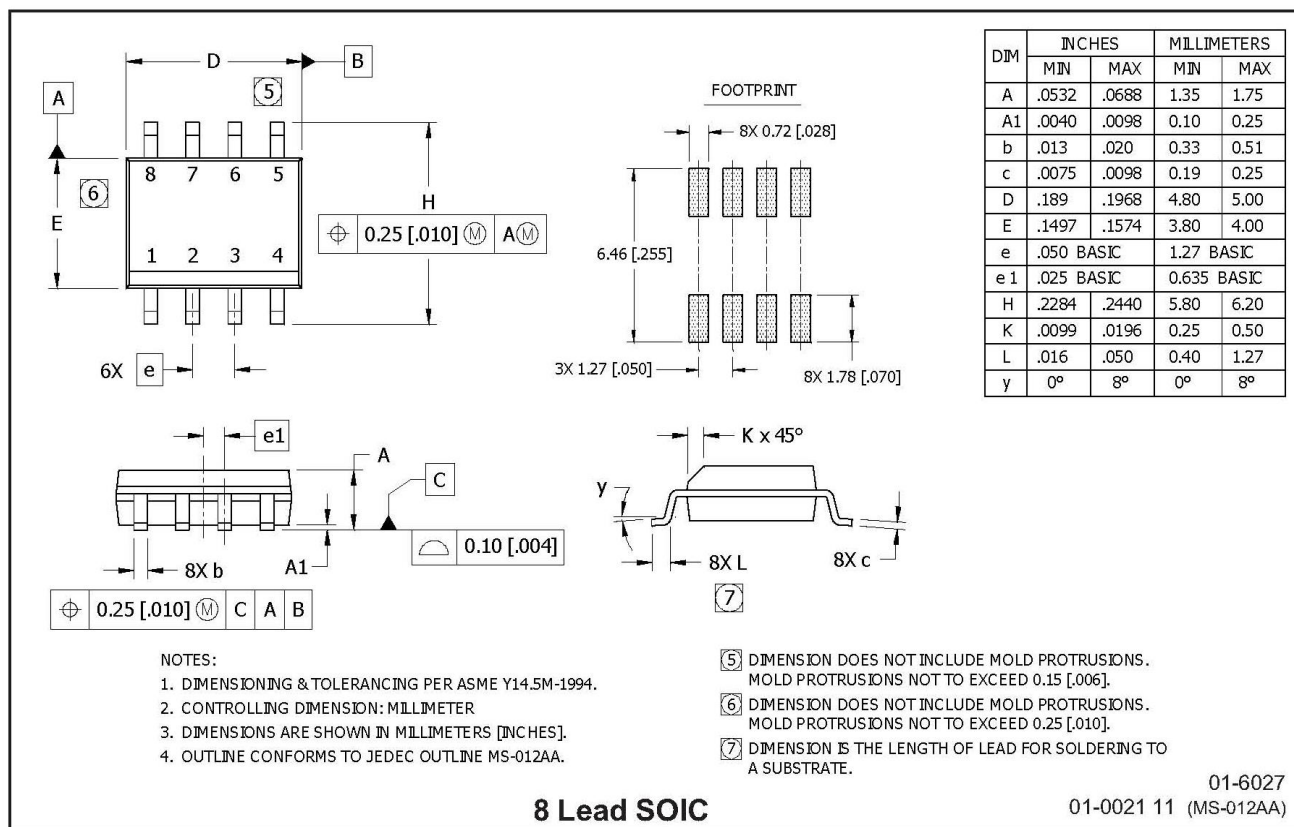
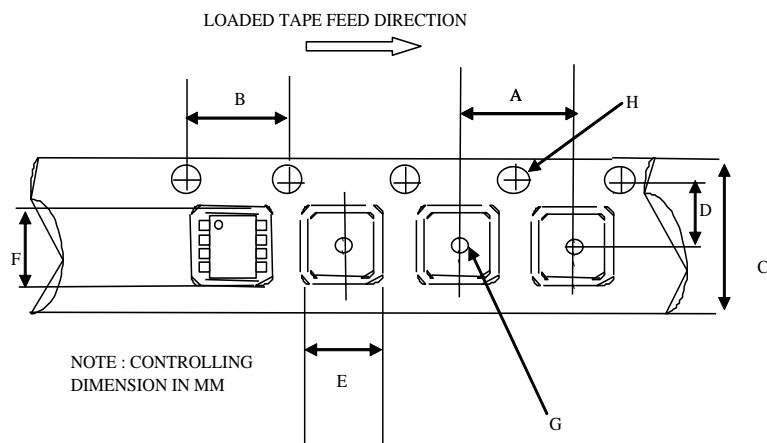


Figure 25A. SD input Negative Going Threshold(-) vs. Voltage

Package Details: 8-Lead SOIC

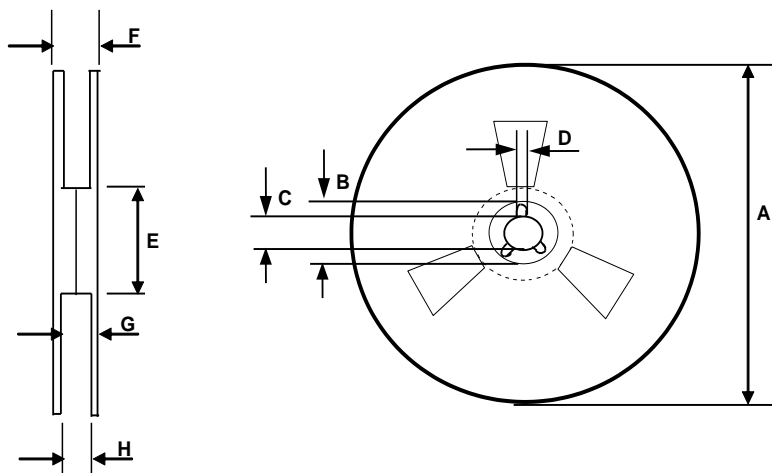


Tape and Reel Details: 8-Lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

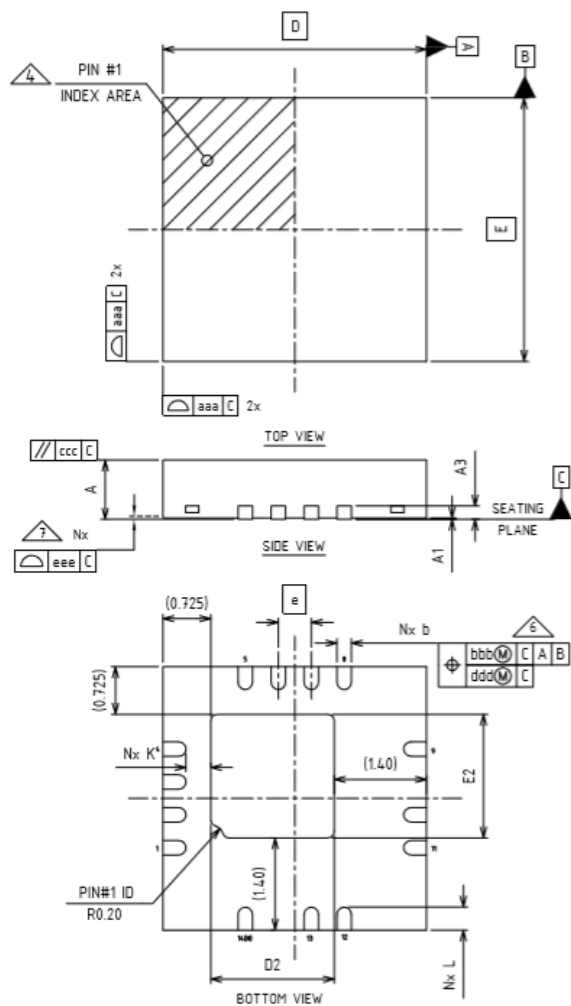
Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062



REEL DIMENSIONS FOR 8SOICN

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

Package Details: 14-Lead MLPQ 4x4

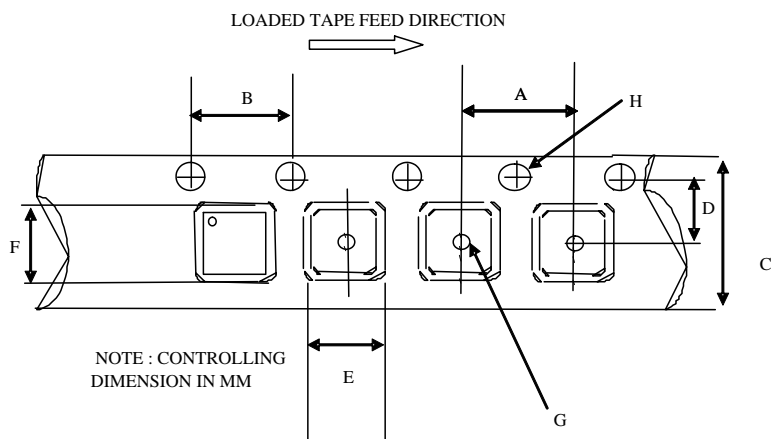


NOTE:

1. Dimensioning and tolerancing conform to ASME Y14.5-2009.
2. All dimensions are in millimeters.
3. N is the total number of terminals.
4. The location of the marked terminal #1 identifier is within the hatched area.
5. ND and NE refer to the number of terminals on each D and E side respectively.
6. Dimension b applies to the metalized terminal and is measured between 0.15mm and 0.30mm from the terminal tip. If the terminal has a radius on the other end of it, dimension b should not be measured in that radius area.
7. Coplanarity applies to the terminals and all other bottom surface metalization.

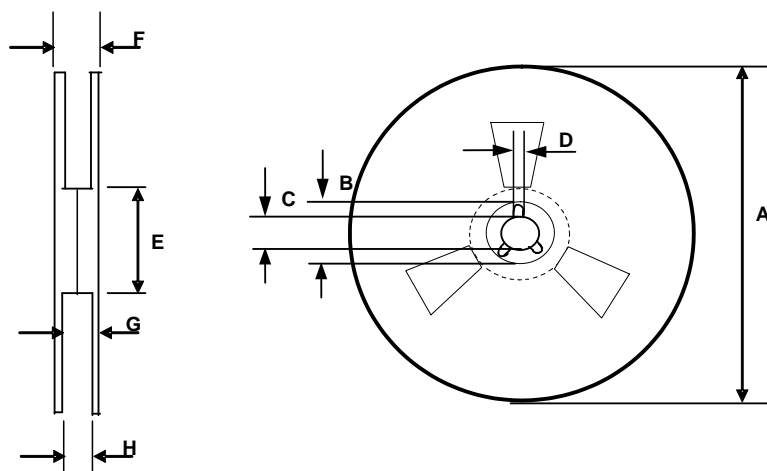
Dimension Table				
Thickness Symbol	V			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	0.80	0.90	1.00	
A1	0.00	0.02	0.05	
A3	---	0.20 Ref	---	
b	0.18	0.25	0.30	6
D	4.00 BSC			
E	4.00 BSC			
e	0.50 BSC			
D2	1.725	1.875	1.975	
E2	1.725	1.875	1.975	
K	0.20	---	---	
L	0.25	0.35	0.45	
aaa	0.05			
bbb	0.10			
ccc	0.10			
ddd	0.05			
eee	0.08			
N	14			3
ND	SEE FIGURE			5
NE	SEE FIGURE			
NOTES	1, 2			

Tape and Reel Details: 14-Lead MLPQ 4x4



CARRIER TAPE DIMENSION FOR MLPQ4x4

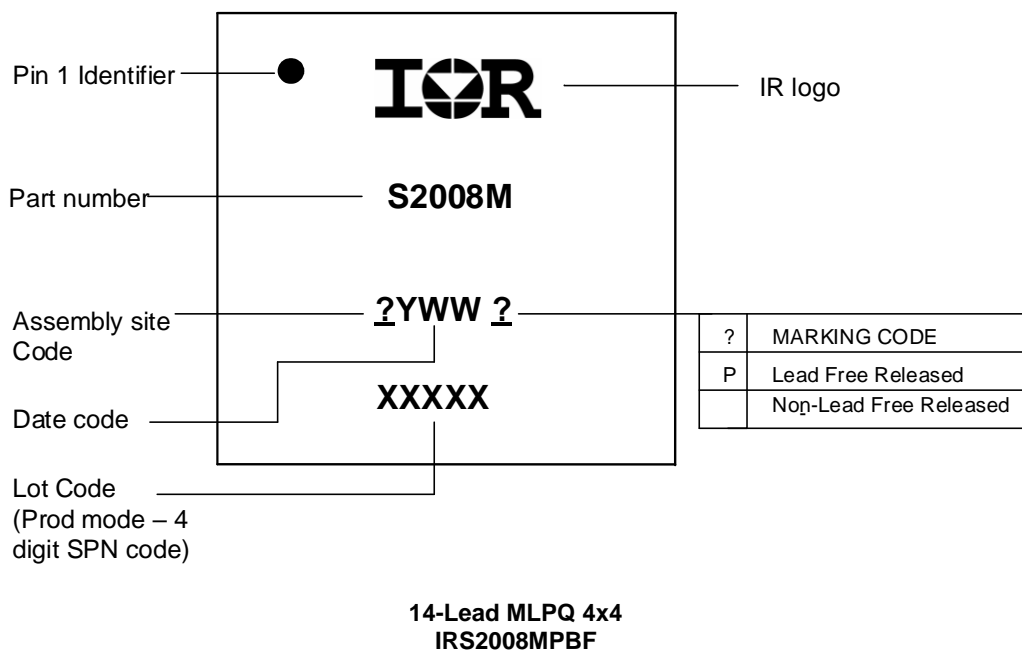
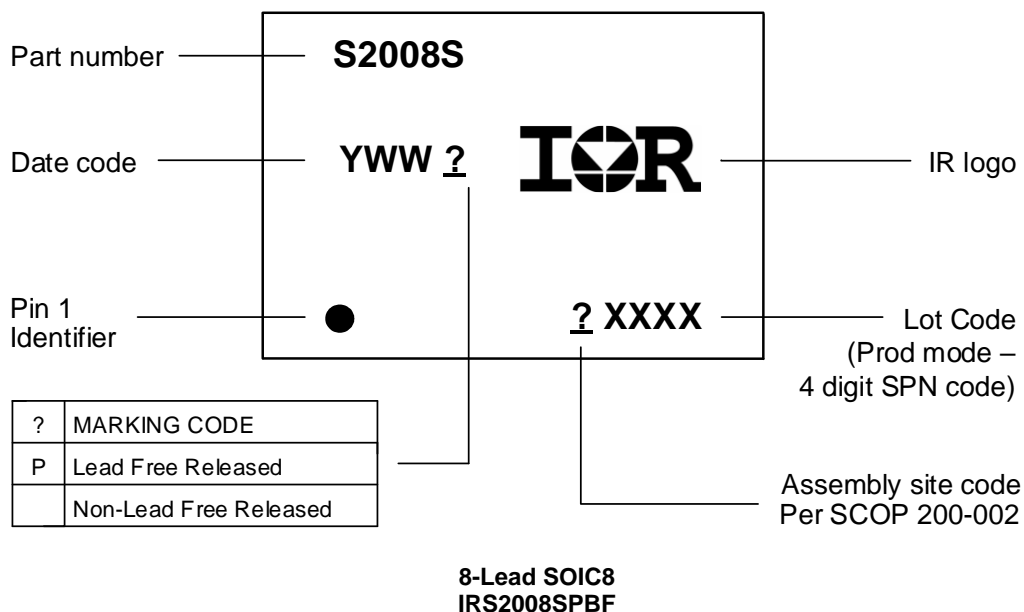
Code	Metric		Imperial	
	Min	Max	Min	Max
A	7.90	8.10	0.311	0.358
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.461	0.484
D	5.45	5.55	0.215	0.219
E	4.25	4.45	0.168	0.176
F	4.25	4.45	0.168	0.176
G	1.50	n/a	0.069	n/a
H	1.50	1.60	0.069	0.063



REEL DIMENSIONS FOR MLPQ4x4

Code	Metric		Imperial	
	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

Part Marking Information



Qualification Information[†]

Qualification Level		Industrial†	
		Comments: This family of ICs is qualified according to relevant tests of JEDEC47/22/20. IR's Consumer qualification level is granted by extension of the higher Industrial level.	
Moisture Sensitivity Level		8 Lead SOIC	MSL2††, 260°C (per IPC/JEDEC J-STD-020)
		14-Lead MLPQ 4x4	
ESD	Human Body Model	Class 2 (per JEDEC standard JESD22-A114)	
	Machine Model	Class A (per EIA/JEDEC standard EIA/JESD22-A115)	
IC Latch-Up Test		Class I (per JESD78)	
RoHS Compliant		Yes	

† According to IR Qualification Requirements for IC products.

†† Higher MSL ratings may be available for the specific package types listed here. Please contact your Infineon sales representative for further information.

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Infineon Technologies AG
81726 München, Germany
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